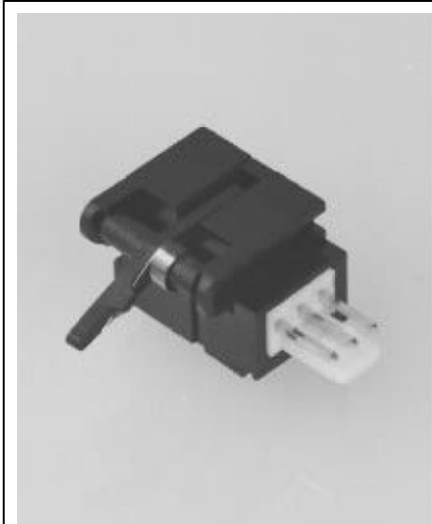


# Notched Optical Flag Switch Type OPB690



## Features

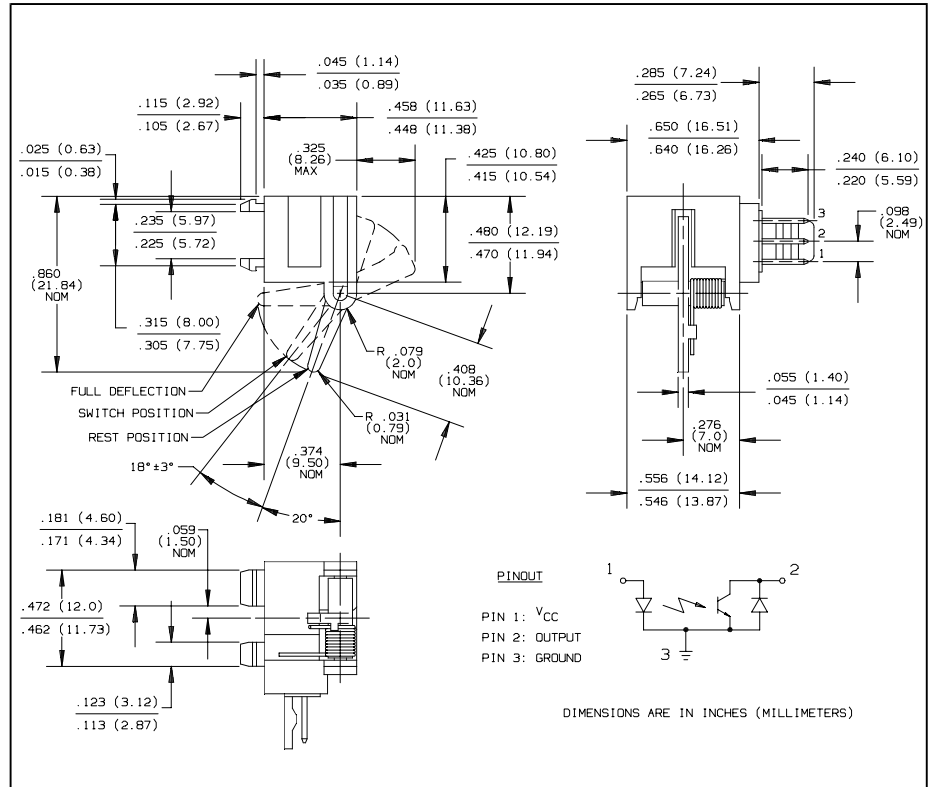
- Phototransistor output
- Mechanical switch replacement
- 3-pin connector (Ho Tien L2561-03), Molex compatible connector 5102 series housing and 5103 series terminal
- Enhanced signal to noise ratio

## Description

The OPB690 consists of an NPN phototransistor and an infrared emitting diode in a molded plastic housing. The phototransistor has an enhanced low current roll-off which improves contrast ratio and immunity to background irradiance. A lever arm actuated flag interrupts the light beam, switching the transistor output between states that can readily drive logic gates.

This switch is designed to easily snap mount into a  $0.037" \pm 0.001"$  (0.94 mm) thick material with a rectangular opening of  $0.320" \pm 0.003" \times 0.472"$  (8.13 mm x 11.99 mm) minimum. Insertion into the punched side of metal is recommended.

Customized lever arms and spring torques can be designed for specific applications.



## Absolute Maximum Ratings (T<sub>A</sub> = 25° C unless otherwise noted)

Storage and Operating Temperature . . . . . -40° C to +100° C

### Input Diode

Forward DC Current . . . . . 50 mA  
Peak Forward Current (1 μs pulse width, 300 pps) . . . . . 3.0 A  
Reverse DC Voltage . . . . . 3.0 V  
Power Dissipation . . . . . 100 mW<sup>(1)</sup>

### Output Phototransistor

Collector-Emitter Voltage . . . . . 30 V  
Emitter Reverse Current . . . . . 10 mA  
Collector DC Current . . . . . 30 mA  
Power Dissipation . . . . . 200 mW<sup>(2)</sup>

### Notes:

- (1) Derate linearly 1.33 mW/° C above 25° C.
- (2) Derate linearly 2.0 mW/° C above 25° C.
- (3) "Off" condition exists when the lever arm is in the rest position (20° from vertical) as shown in the figure.
- (4) "On" condition exists when the lever arm is deflected clockwise 18° +/- 3° from the rest position (20° from vertical) as shown in the figure.
- (5) From the rest position to the switch point, lever torque measured at the end of the arm is 1.5 grams max.



RoHS

For RoHS compliant devices add "Z" to the end of the part number: OPB690Z

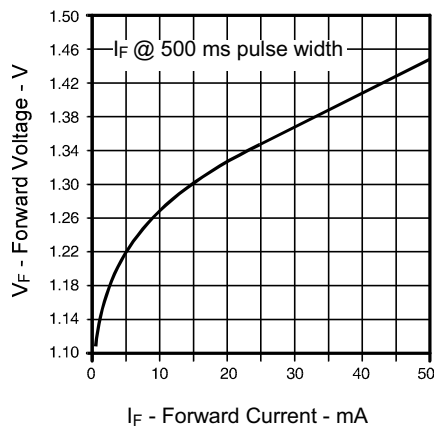
# Type OPB690

Electrical Characteristics ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

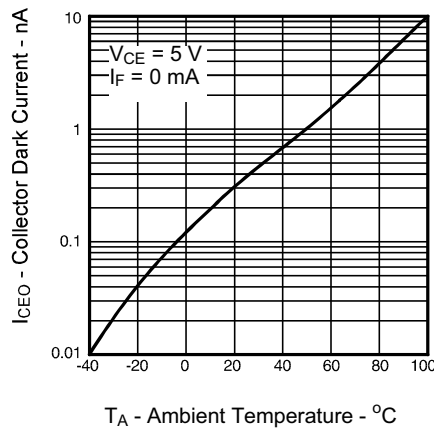
SYMBOL	PARAMETER	MIN	MAX	UNITS	TEST CONDITIONS
<b>Input Diode</b>					
$V_F$	Forward Voltage		1.6	V	$I_F = 10\text{ mA}$
$I_R$	Reverse Current		100	$\mu\text{A}$	$V_R = 3.0\text{ V}$
<b>Output Phototransistor</b>					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30		V	$I_C = 100\ \mu\text{A}$
$I_{ECO}$	Emitter Reverse Current		100	$\mu\text{A}$	$V_{EC} = 0.4\text{ V}$
$I_{CEO}$	Collector-Emitter Dark Current		100	nA	$V_{CE} = 5\text{ V}$
<b>Coupled</b>					
$V_{SAT}$	Saturation Voltage		0.4	V	$I_F = 10\text{ mA}$ , $I_C = 100\ \mu\text{A}$ , Gap unblocked
$I_{C(ON)}$	On-State Collector Current	600		$\mu\text{A}$	$I_F = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$

SLOTTED OPTICAL COMPONENTS

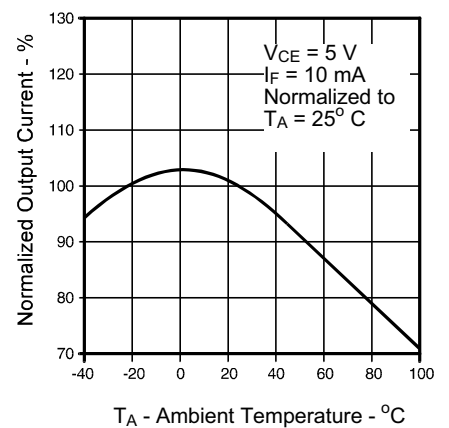
**Forward Current vs Forward Voltage Input Diode**



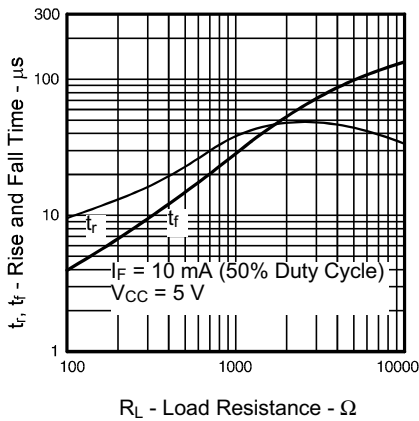
**Collector Dark Current vs Ambient Temperature**



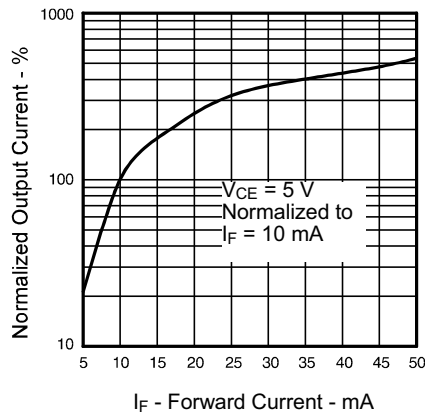
**Normalized Output Current vs Ambient Temperature**



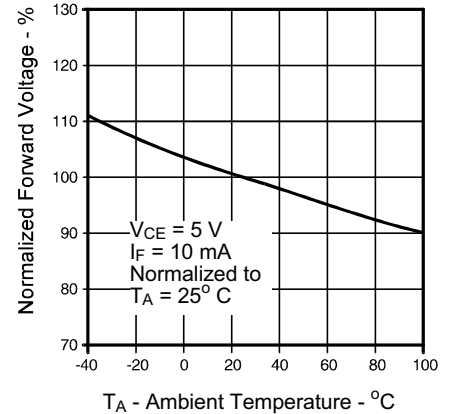
**Rise and Fall Time vs Load Resistance**



**Normalized Output Current vs Forward Current**



**Normalized Forward Voltage vs Ambient Temperature**



Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

Optek Technology, Inc. 1215 W. Crosby Road Carrollton, Texas 75006 (972)323-2200 Fax (972)323-2396